

Honeywell Switch Sensors

1 Product features

Low power consumption

5Hzversion: 1.6uA@1.8V20Hzversion: 3.3uA@1.8V

• Wide working voltage ranges: 1.6V~5.5V

• Magnetic field threshold value optional (Bop)

- 33Gs low threshold value

46Gs high threshold value

Single S-pole magnetic field detection

CMOS push-pull output

• Package: SOT-23

• Working temperature ranges: -40°C~85°C

Excellent ESD performance: HBM 8KV

In accordance with the RoHS standard

2 Typical applications

Laptop and tablet PC switch detection

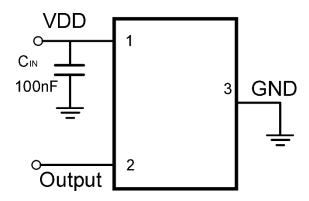
TWS headsets and mobile phones

• Electronic locks and valves position detection

• Water meters, gas meters and flow meters

Non-contact detection

3 Schematic diagram for applied circuit



Notes: In order to remove the noise of the power supply end of the chip, there shall be a capacitance of 100nF between the power supply and the ground, which shall be close to the pin of VDD to the greatest extent.

4 Overview

SL1613 is a Honeywell switch sensor with low power consumption, which is specially designed for systems with compact spaces and that with sensitive electric quantity in batteries. The chip can provide various magnetic field threshold values, switching working frequencies and package forms, so as to adapt to varied types of applications.

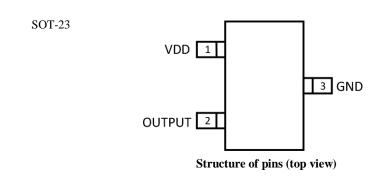
When the applied S-pole magnetic induction intensity is higher than the working point B_{OP} , the chip outputs low level and keeps it, until the S-pole magnetic induction intensity is lower than the release point B_{RP} , when the chip outputs high level. The chip is installed with a temperature compensation circuit and a clock logic circuit internally, to ensure stable working point and switching frequency of the chip. The chip can provide single S-pole magnetic response with extremely low current consumption. SL1613 can work during the power supply ranges of 1.6V to 5.5V, with standard SOT-23 package.



SOT-23



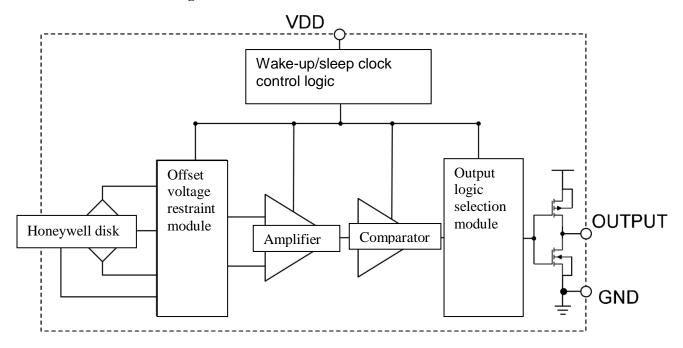
5 Definition of pins and information of signs



Name of pins	No. of pins	Functional description	
VDD	1	Power supply input end	
OUTPUT	2	Output end	
GND	3	Grounding end	

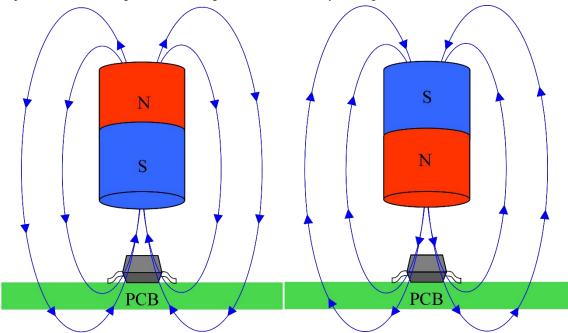


6 Functional block diagram



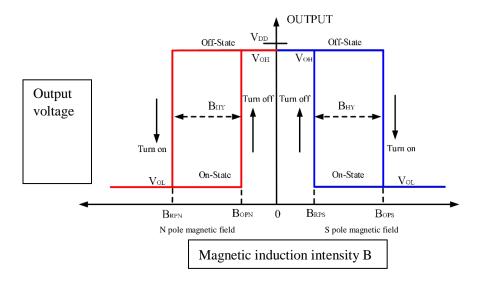
7 Switch output characteristics

As shown in the following figure, when the south pole of the magnet gets closer to the top of the chip, the magnetic induction line passes through from the bottom of the chip to the top; it is regarded that the magnetic induction intensity B is positive at this time. When the north pole of the magnet gets closer to the top of the chip, the magnetic induction line passes through from the top of the chip to the bottom; it is regarded that the magnetic induction intensity B is negative at this time.

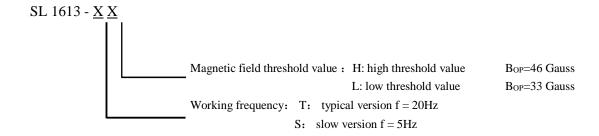




Output characteristics



8 Product model composition





9 Absolute maximum rated value (@TA=+25°C, unless otherwise specified)

Item	Parameter description	Values	Units
$V_{ m DD}$	Supply voltage	6	V
V _{DD_REV}	Reverse supply voltage	-0.3	V
Іоитрит	Output driving current	5	mA
В	Magnetic induction intensity	No upper limit	Gauss
PD	Package	400	mW
T _{STG}	Working temperature ranges	-50~+150	°C
T _J	Junction maximum temperature resistance	+150	°C
ESD HBM	Human body model ESD ability	8000	V

Notes: It may lead to permanent damages in condition of working exceeding the absolute maximum rated value. Long-time working at the absolute rated conditions may lead to influences on reliability of the chip.

10 Reference working conditions (@TA=+25°C, unless otherwise specified)

Item	Parameter Working conditions description		Values	Units
V_{DD}	Supply voltage ranges	Chip working	1.6~5.5	V
TA	Working temperature ranges	Chip working	-40~85	$^{\circ}$

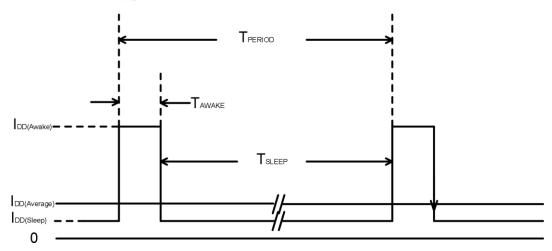
11 Electrical parameters (@TA=+25°C, V_{DD} =1.8V unless otherwise specified)

	SL 1613-TX series					
Item	Parameter description	Working conditions	Min. value	Typical value	Max. value	Units
VDD	Supply voltage	Working state	1.6	_	5.5	V
VOL	Output low level	I _{OUT} =1mA	_	0.02	0.1	V
VOH	Output high level	I _{OUT} =1mA	V _{DD} -0.1	V _{DD} -0.02	_	V
Idd(AVG)	Average current	TA=+25°C, VDD=1.8V	_	3.30	_	μΑ
IDD(Awake)	Wake-up current	TA=+25°C, VDD=1.8V	_	2.0	_	mA
IDD(Sleep)	Sleep current	TA=+25°C, VDD=1.8V	_	1.00		μΑ
Tawake	Wake-up time	Working state	_	50	_	μs
Tperiod	Period	Working state	_	50	_	ms



	SL1613- SX series					
Item	Parameter description	Working conditions	Min. value	Typical value	Max. value	Units
VDD	Supply voltage	Working state	1.6	_	5.5	V
VOL	Output low level	I _{OUT} =1mA	_	0.02	0.1	V
VOH	Output high level	I _{OUT} =1mA	V _{DD} -0.1	V _{DD} -0.02	_	V
Idd(AVG)	Average current	TA=+25°C, VDD=1.8V	_	1.6	_	μΑ
IDD(Awake)	Wake-up current	TA=+25°C, VDD=1.8V	_	2.0	_	mA
IDD(Sleep)	Sleep current	TA=+25°C, VDD=1.8V	_	1.0		μΑ
Tawake	Wake-up time	Working state	_	50	_	μs
TPERIOD	Period	Working state	_	200	_	ms

Notes: After the chip is powered on (VDD is $1.6V\sim5.5V$), it starts sampling for output, and the output state takes effect after the second working period.



12 Magnetic parameters (@TA=+25°C, V_{DD}=1.8V unless otherwise specified)

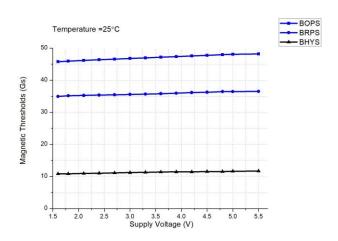
Item	Parameter description	Working conditions	Min. value	Typical value	Max. value	Units
SL1613- XH series						
$\mathrm{B}_{\mathrm{OPS}}$	Magnetic field working point	TA=+25°C, VDD=1.8V	40	46	52	
$\mathrm{B}_{\mathrm{RPS}}$	Magnetic field release point	TA=+25°C, VDD=1.8V	26	34	38	Gauss
$B_{HY}\left(B_{OPS} \text{-} B_{RPS} \right)$	Magn etic hyster esis		-	12	-	

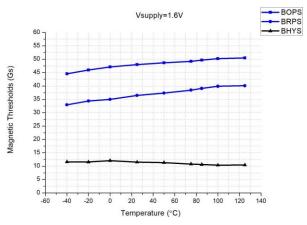


Item	Parameter description	Working conditions	Min. value	Typical value	Max. value	Units
SL1613-XL series						
B _{OPS}	Magnetic field working point	TA=+25°C, VDD=1.8V	26	33	38	
B_{RPS}	Magnetic field release point	TA=+25°C, VDD=1.8V	16	23	28	Gauss
$B_{HY}\left(B_{OPS} \text{-} B_{RPS} \right)$	Magnetic hysteresis		-	10	-	

13 Performance curve diagram

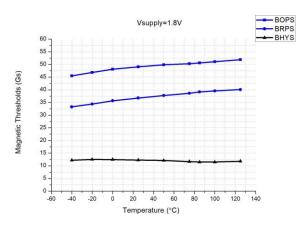
SL1613- XH series (high threshold value version)

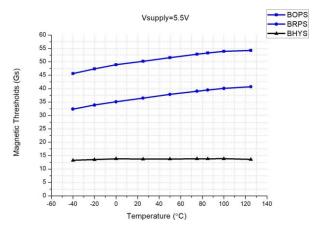




Magnetic threshold value vs. supply voltage $@T_A=25^{\circ}C$

Magnetic threshold value vs temperature @VDD=1.6



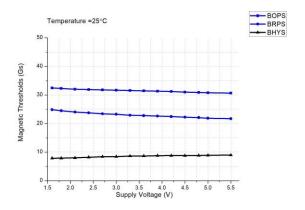


Magnetic threshold value vs temperature @VDD=1.8V

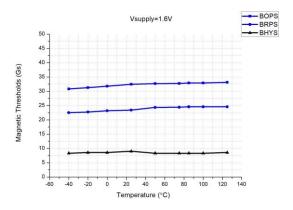
Magnetic threshold value vs temperature @VDD=5.5



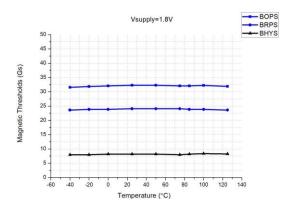
SL1613 -XL series (low threshold value version)



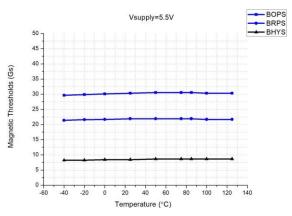
Magnetic threshold value vs. supply voltage @T_A=25°C



Magnetic threshold value vs temperature @VDD=1.6v

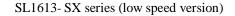


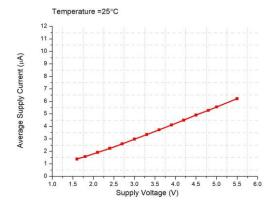
Magnetic threshold value vs temperature @VDD=1.8V



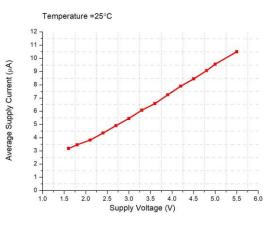
SL1613- TX series (typical version)

Magnetic threshold value vs temperature @VDD=5.5v





Average working current vs. supply voltage @ T_A=25°C



Average working current vs. supply voltage @ T_A=25°C



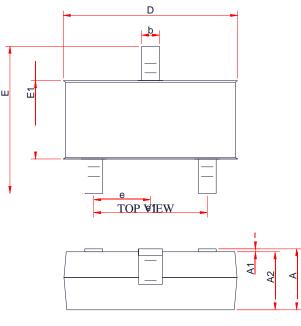
14 Ordering information

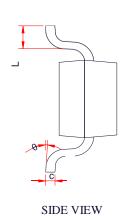
Model	Package	Number of	Magnetic field	Switching	Temperature
	mode	pins	threshold value (Bop)	frequency	
SL1613-TH	SOT-23	3	46Gauss	20Hz	-40°C~85°C
SL1613 -TL	SOT-23	3	33Gauss	20Hz	-40°C~85°C
SL1613- SH	SOT-23	3	46Gauss	5Hz	-40°C~85°C
SL1613- SL	SOT-23	3	33Gauss	5Hz	-40°C~85°C



Package dimension profile drawing

SOT-23





CT	DE	V	TEX	X

Symbol	Dim	ensions in Millimeters	
Symbol	Min.	Тур.	Max.
A	-	-	1.25
A1	0.00	-	0.1
A2	1.00	1.10	1.15
b	0.30	-	0.50
С	0.10	-	0.20
D	2.82	2.95	3.02
Е	2.65	2.80	2.95
E1	1.50	1.65	1.70
e	0.85	0.95	1.05
e1	1.80	1.90	2.00
L	0.30	0.45	0.60
θ	0 °	-	8 °